

TDR Ch4 (updates 2)

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1.1 Already discussed

1.2 Already discussed

1.3 To be detailed (next week)

1.4 Problem of the threshold power

1.5 Already discussed but I could add other considerations (next week)

1.6 Completed with the final configuration and results.

1.4 Estimated threshold power

As Yurke first showed in 1984 [REFERENCE] to make possible the production of squeezed light by a parametric down conversion process, it needs to work in *subthreshold* regime. So, it is important to calculate the threshold power for our OPO.

The value of the threshold depends on cavity parameters and the non-linear conversion efficiency of the crystal [REFERENCE WuXiaoKimble]:

$$P_{th} = \frac{\pi^2}{4F^2 B E_{NL}} \quad B = \frac{T_1}{(1 - \sqrt{R_1 R_2})} \quad (1.1)$$

where F is the cavity finesse at 1064 nm, B is the *buildup* parameter¹ (the ratio between the one-way circulating power into the cavity and the incident pump power, in the absence of coupling) and E_{NL} is the *nonlinear conversion efficiency*². In case of perfect mismatch ($\Delta k = 0$), for our cavity $E_{NL} = 0.0115W^{-1}$, $B = 2.6$ and considering that the finesse of our cavity is about $F = 75$ we can find that the predicted threshold power is 14.7 mW.

TOO LOW!!!
For GEO is about 60 mW

²The nonlinear conversion efficiency is defined as

$$E_{NL} = \frac{2\omega d_{eff}^2 l^2}{\pi \epsilon_0 c^3 w_0^2 n^3} \text{sinc}^2 \left(\frac{\Delta k l}{2} \right)$$

where l d_{eff} is the *effective nonlinear coefficient* ($d_{eff} = 10.3$ pm/V for KTP), l the crystal length and Δk the momentum mismatch between the pump beam and the beam at the fundamental frequency.

For SHG

$$P_{2\omega} = P_{\omega}^2 \frac{2\omega^2 d_{NL}^2 l^2}{\pi \epsilon_0 c^3 \omega^2 n^3} \text{sinc}^2 \left(\frac{\Delta k l}{2} \right)$$

$$\frac{P_{2\omega}}{P_{\omega}} = E_{NL} P_{\omega}, \quad d_{eff} = \frac{2d_{33}}{\pi}, \quad \text{In our case} \quad \frac{P_{\omega}}{P_{2\omega}} = E_{NL} P_{2\omega}$$

this experiment. The poling reduces the effective nonlinear coefficient of the crystal by a factor

$$d_{eff} = \frac{2d_{33}}{\pi}, \quad (3.6)$$

where the d_{33} coefficient is the scalar component of the nonlinear coefficient used in this experiment. For KTP, $d_{33} = 16.2$ pm/V which makes the effective coefficient $d_{eff} = 10.3$ pm/V [Sutherland, 2003].

I used this value

Measurement of nonlinear optical coefficients by phase-matched harmonic generation

Robert C. Eckardt and Robert L. Byer

KDP	$d_{36} = 0.38$	
KD*P	$d_{36} = 0.37$	
LiIO ₃	$d_{31} = -4.1$	
5%MgO:LiNbO ₃	$d_{31} = -4.7$	
BaB ₂ O ₄	$d_{\text{eff}} = 1.94$ $ d_{22} = 2.2(\text{b})$	
KTP	$d_{\text{eff}} = 3.2$ $ d_{15} = 1.9(\text{c})$ $ d_{24} = 3.5$	← NO POLING

I must investigate about the correct parameters to use

1.6 Temperature Control

To reach the phase matching condition, as in the case of second harmonic generation, the crystal temperature must be kept constant, at a value of about 35° C. Also in this case, the desired temperature is maintained by an active control loop, using a sensor and an actuator. In the control scheme used for the OPO, two NTC thermistors ³ and a peltier element ⁴ (driven by an external DC power supply) are used.

One of the two thermistors (In-Loop) is inserted in an analog circuit (Wheatstone bridge) whose output voltage (related to the NTC resistance, and then to the measured temperature) is used for a PID control loop, running under LabView. The other thermistor (Out-of-Loop) is used to measure the temperature independently of the control loop. This last measurement it was

³ *Conrad Elektronik, Type: NTC-SEMI833, Part number: 188506*

⁴RS 197-0332

performed using a high precision digital multimeter⁵. This control loop make possible to reach a temperature stability of less than a mK for the Out-of-Loop measurement and of about 2 mK with the In-Loop thermistor.

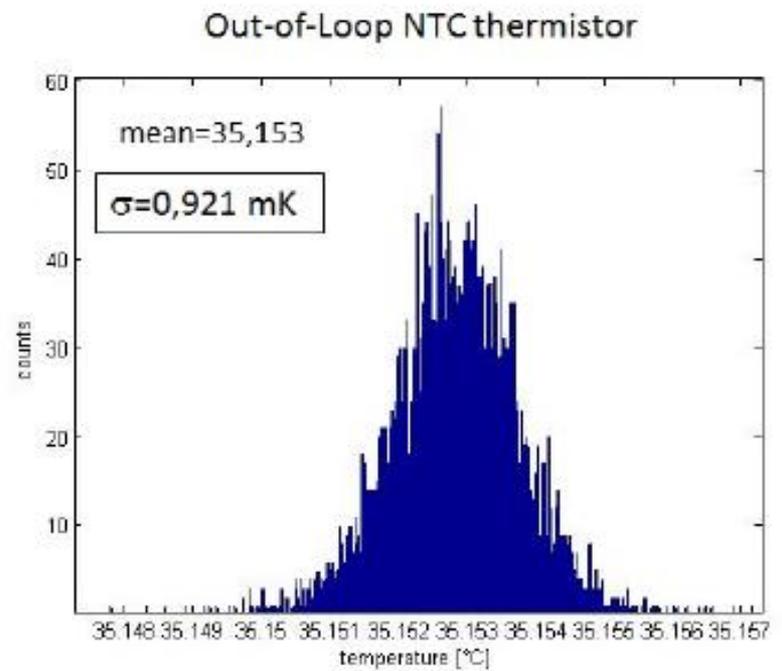
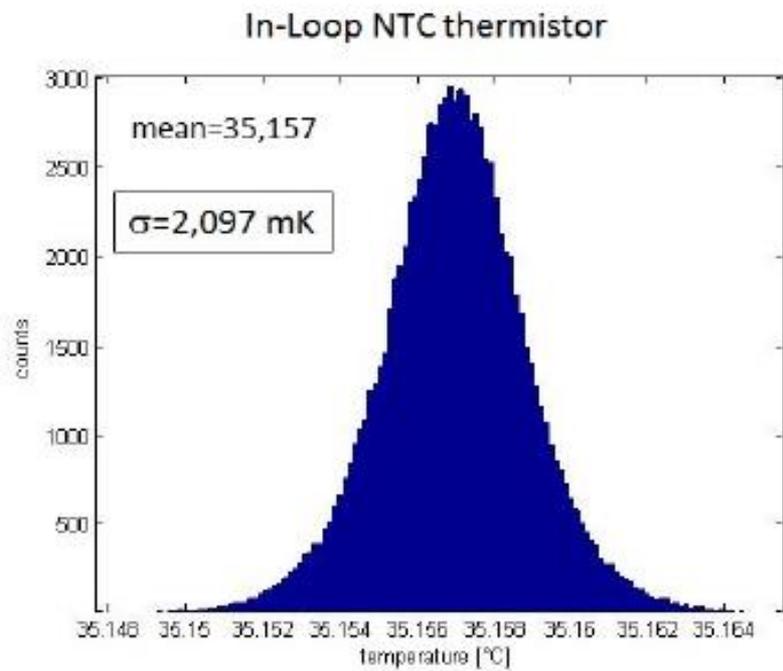


Figure 1.7. Measurement of the temperature stability obtained by a PID control loop.